

### 30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

7 A

#### **Features**

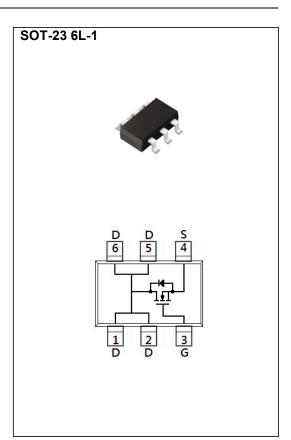
- $R_{DS(ON)}$ ,  $V_{GS}$ @10V,  $I_D$ @8A<25m $\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@6A<35m\Omega$
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Advanced trench process technology
- Specially designed for switch load, PWM application, etc

#### **Mechanical Data**

• Case: SOT-23 6L-1 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0005 ounces, 0.014 grams



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMET	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage	V <sub>DS</sub>	30	V		
Gate-Source Voltage		V <sub>GS</sub>			<u>+</u> 20
Continuous Drain Current (Note 4)		I <sub>D</sub>	7	Α	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	28		
Power Dissipation	T <sub>a</sub> =25°C		2	W	
	Derate above 25°C	P <sub>D</sub>	16	mW/ °C	
Operating Junction and Storage	T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C		
Typical Thermal Resistance - Junction to Ambient (Note 3)		RеJA	62.5	°C/W	



## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	1.7	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =8A	_	18.5	25	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A	-	24	35	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 5)						
Total Gate Charge	Qg	V <sub>DS</sub> =15V, I <sub>D</sub> =8A, V <sub>GS</sub> =4.5V (Note 2)	_	4.3	-	nC
Gate-Source Charge	Q <sub>gs</sub>		_	1.3	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	1.6	-	
Input Capacitance	Ciss	\/ -25\/ \/ -0\/	_	392	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHZ	-	76	-	
Reverse Transfer Capacitance	Crss	I – HVII IZ	-	54	-	
Turn-On Delay Time	td <sub>(on)</sub>	\	_	5.9	-	
Turn-On Rise Time	tr	$V_{DS}$ =15V, $I_{D}$ =1A, $V_{GS}$ =10V, $R_{G}$ =6 $\Omega$	_	11	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>	(Note 2)	-	17	-	
Turn-Off Fall Time	tf	,	_	3.8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	Is		-	-	1.5	А
Diode Forward Current	IS					
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.73	1	V

#### NOTES:

- 1. Pulse width < 300 us, Duty cycle < 2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



#### TYPICAL CHARACTERISTIC CURVES

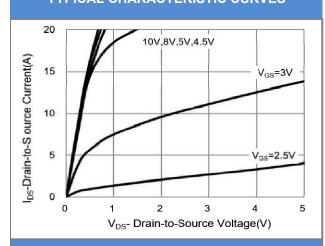
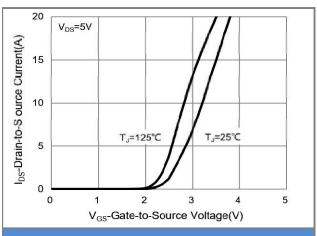


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

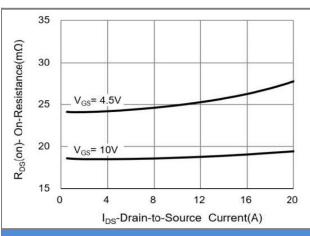


Fig.3 On-Resistance vs. Drain Current

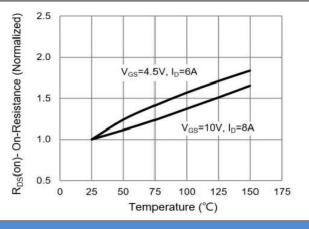


Fig.4 On-Resistance vs. Junction temperature

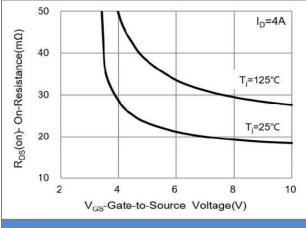
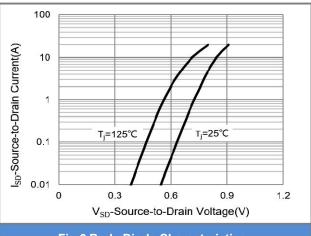


Fig.5 On-Resistance Variation with V<sub>GS</sub>



**Fig.6 Body Diode Characteristics** 



#### **TYPICAL CHARACTERISTIC CURVES**

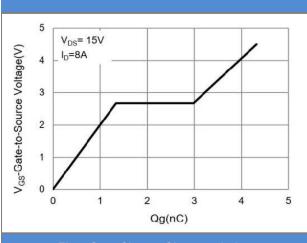


Fig.7 Gate-Charge Characteristics

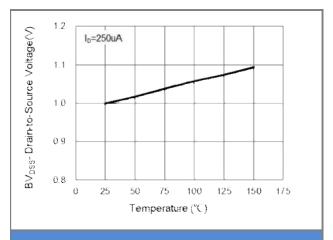


Fig.8 Breakdown Voltage Variation with Temperature

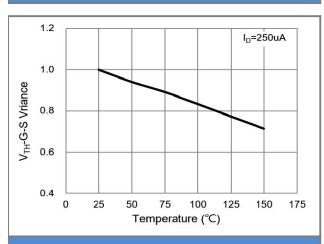


Fig.9 Threshold Voltage Variation with Temperature

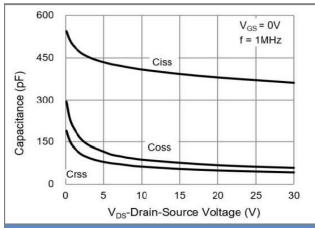


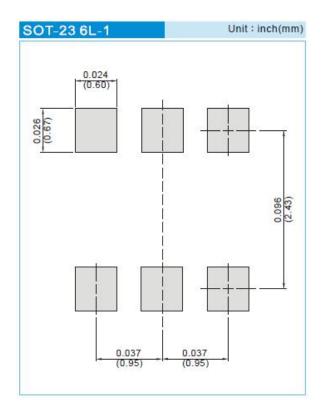
Fig.10 Capacitance vs. Drain-Source Voltage



## **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type		
CSM320N7S236	SOT-23 6L-1	3K pcs / 7" reel		

## **Mounting Pad Layout**





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